

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,979,628 B2
APPLICATION NO. : 10/726788
DATED : December 27, 2005
INVENTOR(S) : Kim et al.

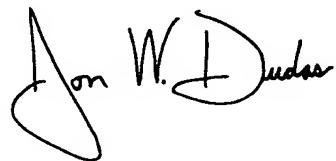
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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

At column 1, line 35, please replace "nonvolatile" with --non-volatile--
At column 1, line 43, please replace "nonvolatile" with --non-volatile--
At column 11, line 29, please replace "trench arid" with --trench and--
At column 14, line 11, please replace "field oxides layers" with --field oxide layers--
At column 14, line 13, please replace "key region" with --key region;--

Signed and Sealed this

Sixteenth Day of January, 2007



JON W. DUDAS
Director of the United States Patent and Trademark Office